



### PE5N50KD N-Channel Enhancement Mode Power MOSFET

#### PE5N50KD Description

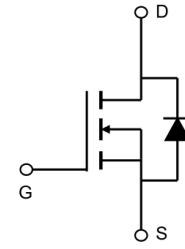
The PE5N50KD uses super junction technology to provide excellent  $R_{DS(ON)}$  and low gate charge. It can be used in a wide variety of applications.

#### PE5N50KD General Features

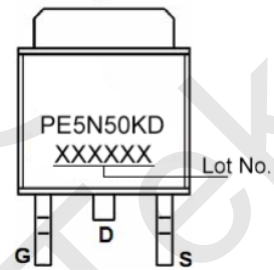
- $V_{DS} = 500V$ ,  $I_D = 5A$
- $R_{DS(ON)} < 1.6\Omega @ V_{GS}=10V$
- Low Power Loss by High Speed Switching and Low On-Resistance

#### PE5N50KD Application

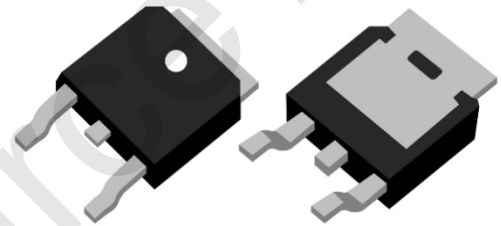
- PFC Power Supply Stages
- Switching Applications
- Adapter



Schematic diagram  
D



Marking and pin assignment



TO-252-2L

#### PE5N50KD Absolute Maximum Ratings (TC=25°C unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	500	V
Gate-Source Voltage	$V_{GS}$	±30	V
Drain Current-Continuous	$I_D$	5	A
Drain Current-Continuous (TC=100°C)	$I_D$	3	A
Pulsed Drain Current (Note 1)	$I_{DM}$	20	A
Maximum Power Dissipation	$P_D$	48	W
Avalanche Energy (L=24mH)	$E_{AS}$	230	mJ
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	°C

#### PE5N50KD Thermal Characteristic

Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.6	°C/W
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### PE5N50KD Electrical Characteristics (TC=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	500	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=500V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 30V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>On Characteristics</b> (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	-	4	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=2.5A$	-	1.25	1.6	$\Omega$
<b>Dynamic Characteristics</b> (Note 4)						
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V,$ $F=1MHz$	-	545	-	pF
Output Capacitance	$C_{oss}$		-	64	-	pF
Reverse Transfer Capacitance (Note 4)	$C_{rss}$		-	5	-	pF
Gate Resistance	$R_G$	$F=1.0MHz$	-	2.5	-	$\Omega$
<b>Switching Characteristics</b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=250V, I_D=5A,$ $R_G=25\Omega$	-	14	-	nS
Turn-on Rise Time	$t_r$		-	18	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	32	-	nS
Turn-Off Fall Time	$t_f$		-	11	-	nS
Total Gate Charge	$Q_g$	$V_{DD}=400V, I_D=5A, V_{GS}=10V$	-	16.5	-	nC
Gate-Source Charge	$Q_{gs}$		-	3.8	-	nC
Gate-Drain Charge	$Q_{gd}$		-	5.6	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	$V_{SD}$	$V_{GS}=0V, I_S=5A$	-	-	1.4	V
Diode Forward Current (Note 2)	$I_S$		-	-	5	A
Reverse Recovery Time	$t_{rr}$	$V_R=300V, I_F=5A,$ $di/dt=100A/\mu s$	-	86	-	nS
Reverse Recovery Charge	$Q_{rr}$		-	0.18	-	$\mu C$

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to product.



### PE5N50KD Typical Electrical and Thermal Characteristics

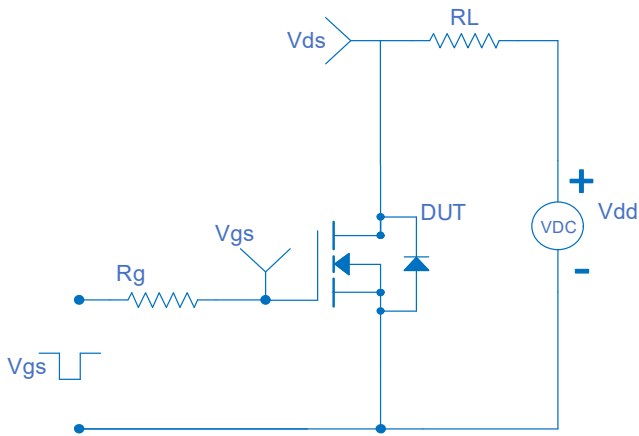


Figure 1 Switching Test Circuit

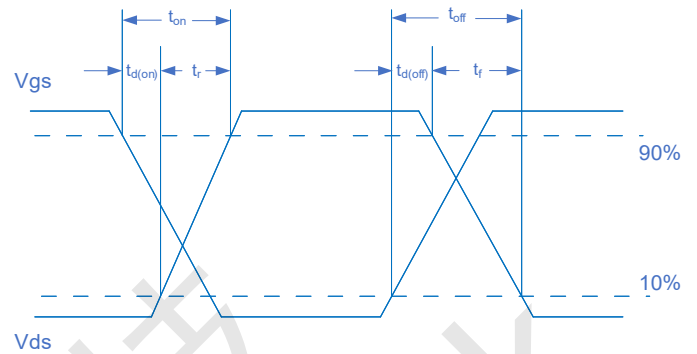


Figure 2 Switching Waveform

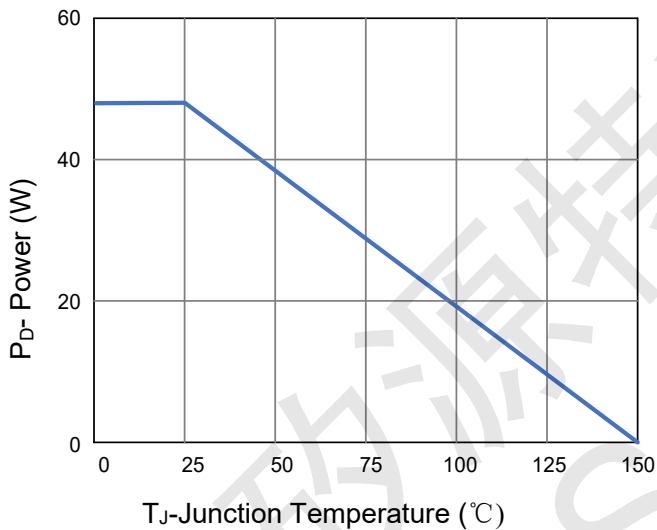


Figure 3 Power De-rating

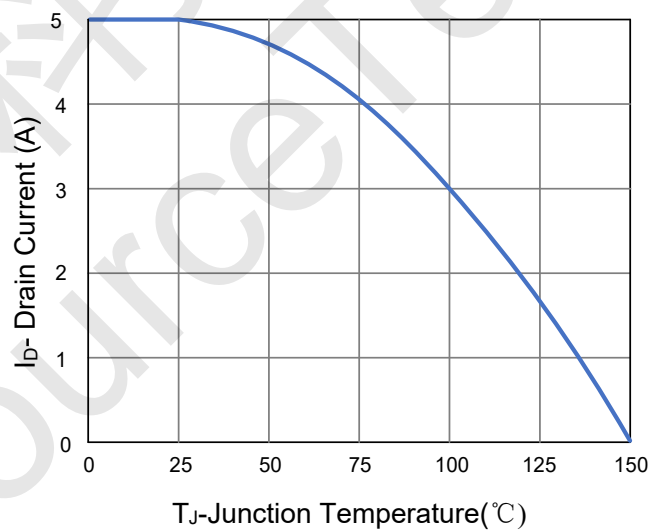


Figure 4 Drain Current

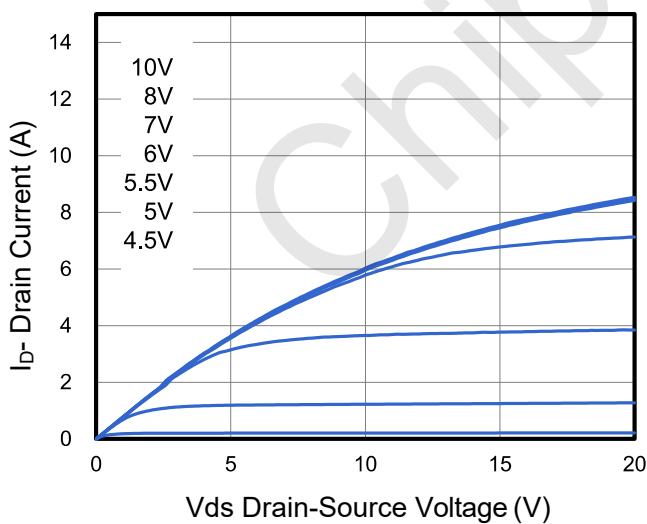


Figure 5 Output Characteristics

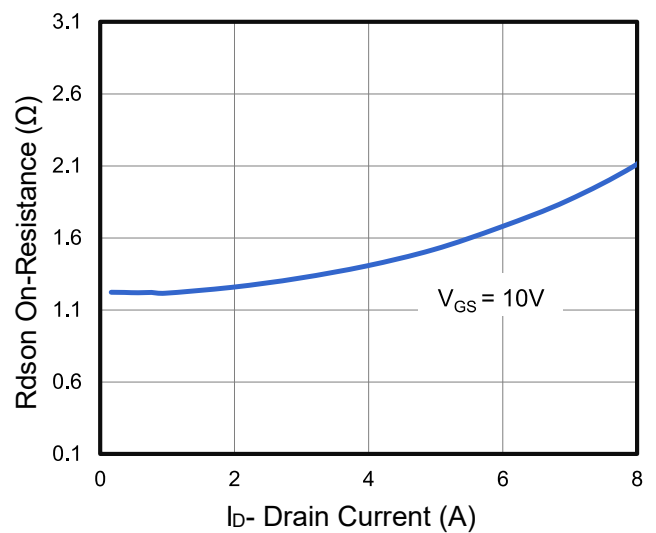


Figure 6 Rdson vs Drain Current

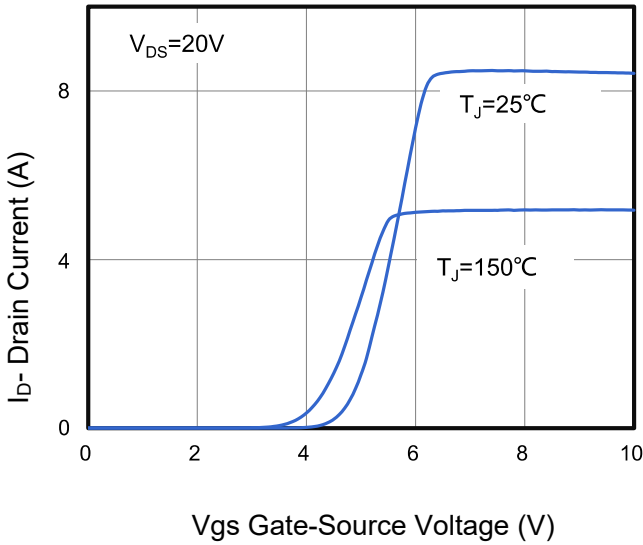


Figure 7 Transfer Characteristics

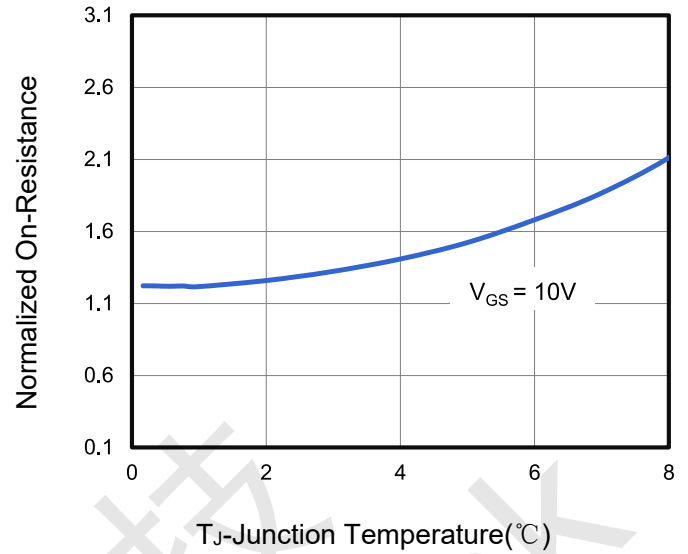


Figure 8 Rdson vs Junction Temperature

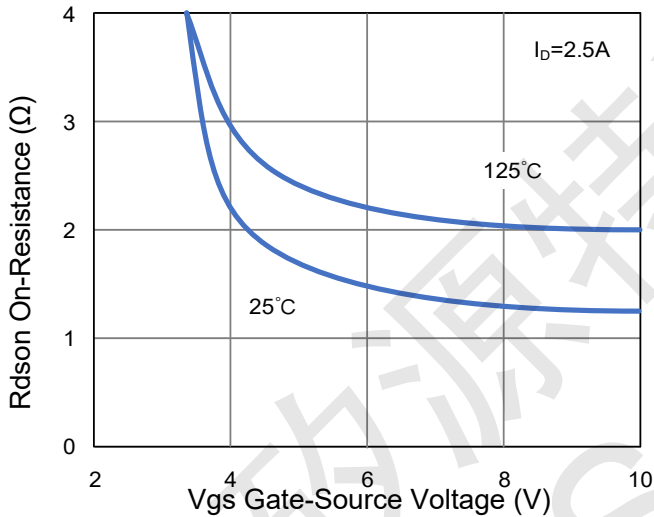


Figure 9 Rdson vs Vgs

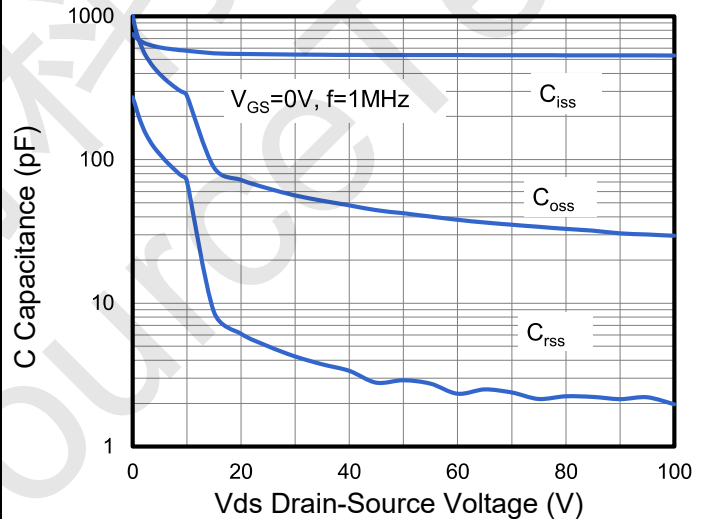


Figure 10 Capacitance vs Vds

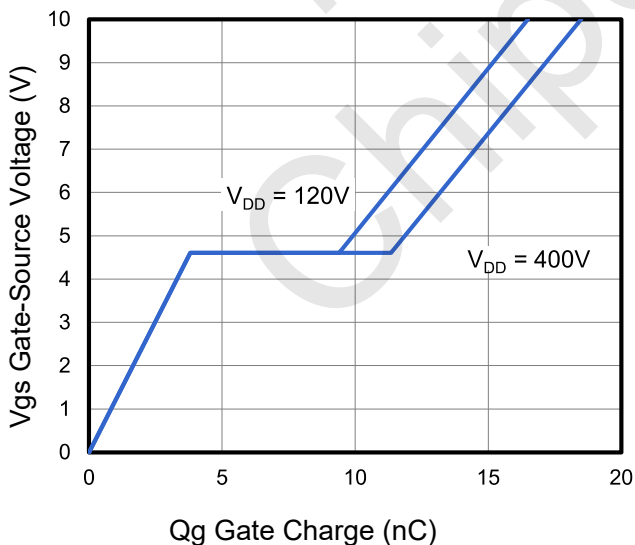


Figure 11 Gate Charge

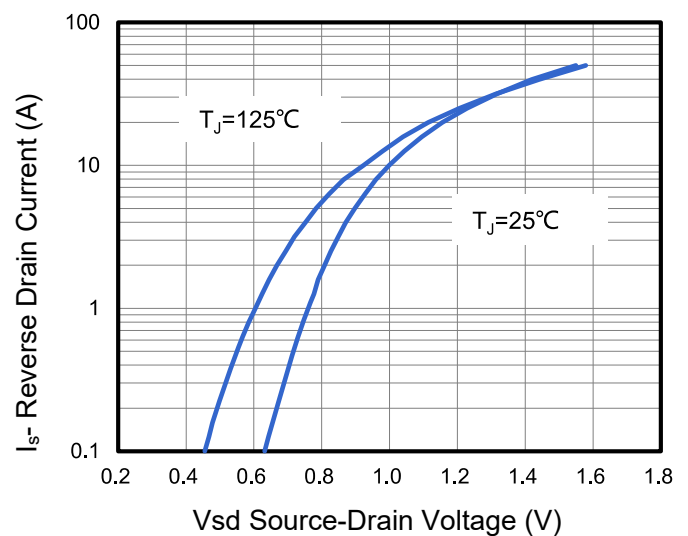


Figure 12 Source- Drain Diode Forward

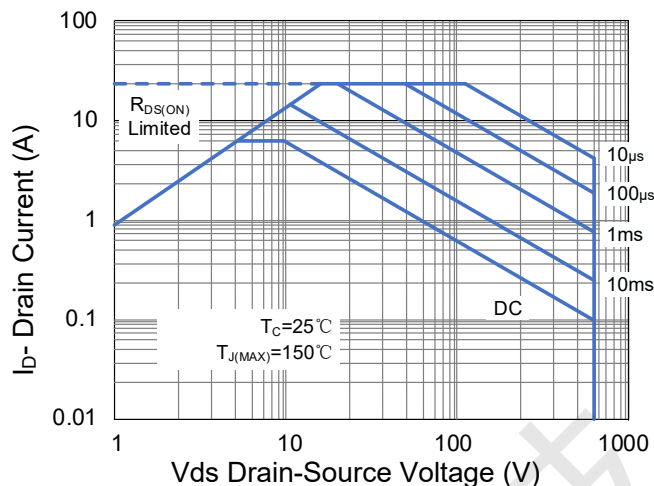


Figure 13 Safe Operation Area

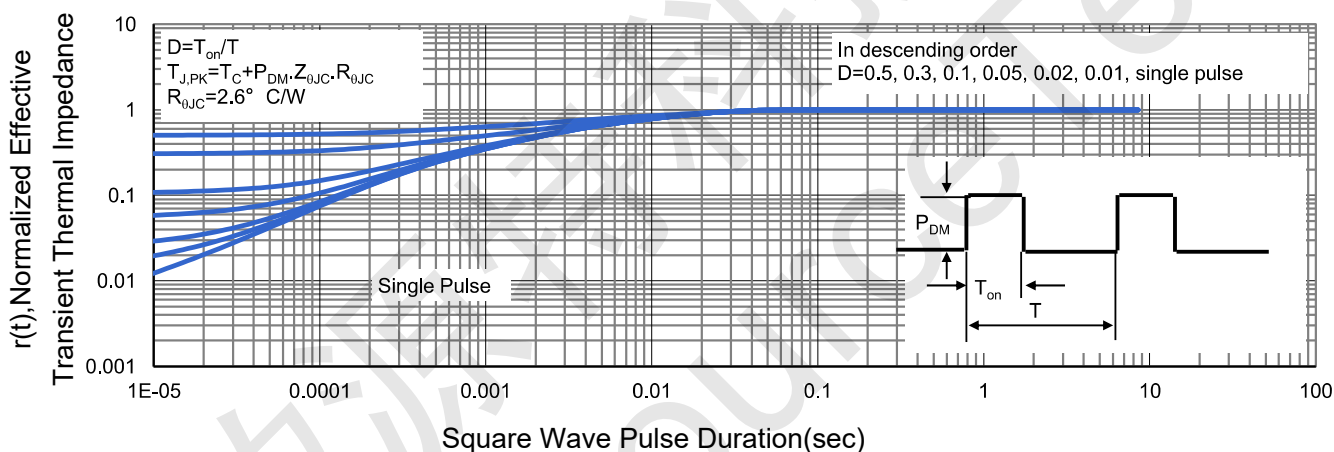
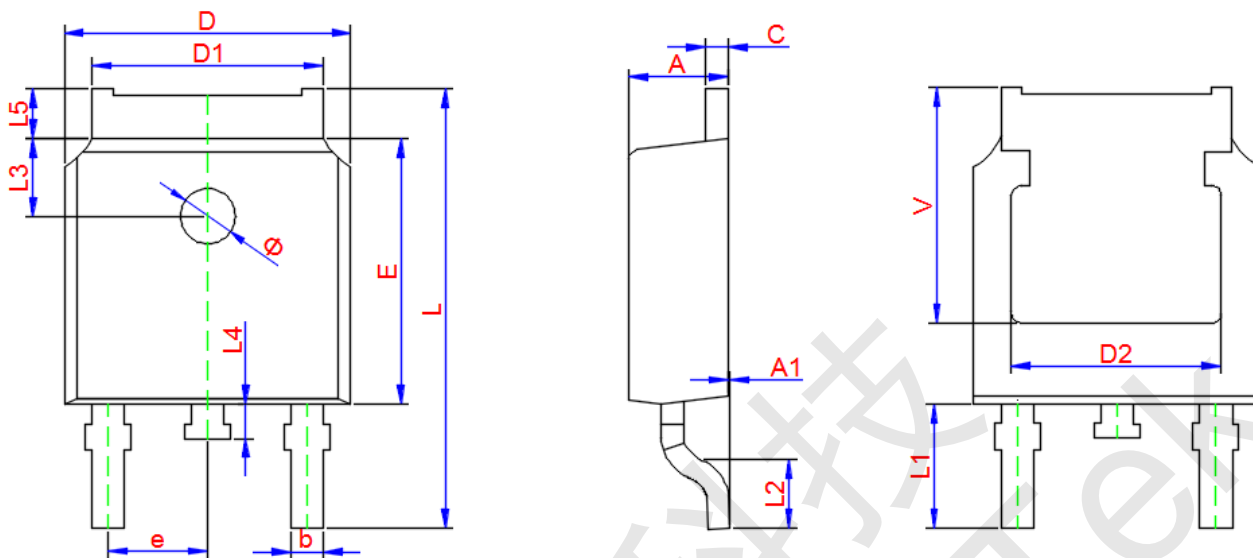


Figure 14 Normalized Maximum Transient Thermal Impedance



PE5N50KD TO-252-2L Package Information



Symbol	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	2.200	2.300	2.400
A1	0.000	--	0.127
b	0.660	0.760	0.860
D	6.500	6.600	6.700
D1	5.100	5.330	5.460
C	0.450	0.500	0.600
D2	4.830 TYP.		
E	6.000	6.100	6.200
e	2.186	2.286	2.386
L	9.800	10.100	10.400
L1	2.900 TYP.		
L2	1.400	1.500	1.600
L3	1.800 TYP.		
L4	0.600	0.800	1.000
L5	0.900	--	1.250
$\Phi$	1.100.	--	1.300
$\theta$	0°	--	8°
V	5.350		